

MITSUBISHI MICROCOMPUTERS

M37710E4BXXXFP

M37710E4BFS

PROM VERSION of M37710M4BXXXFP

DESCRIPTION

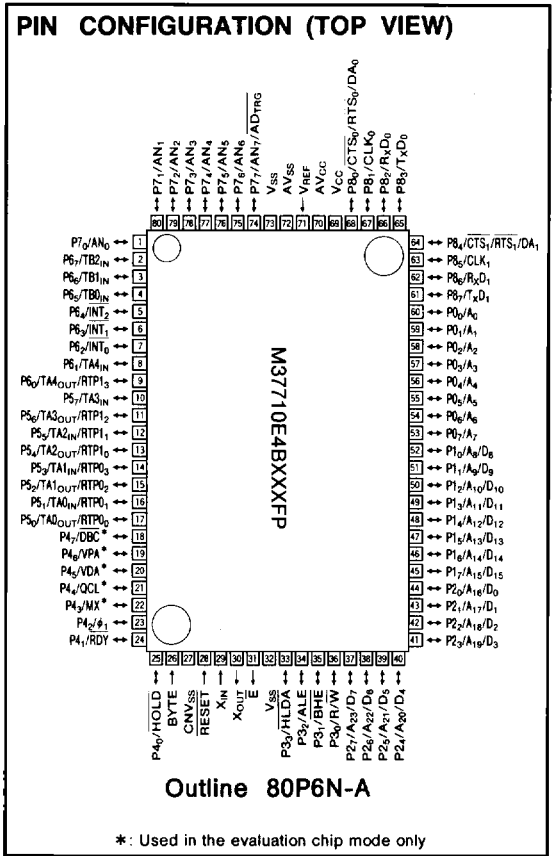
The M37710E4BXXXFP is a built-in PROM single-chip microcomputers designed with high-performance CMOS silicon gate technology. This is housed in a 80-pin plastic molded QFP. The features of this chip are similar to those of the M37710M4BXXXFP except that this chip has a 32K-byte PROM built in.

This single-chip microcomputer has a large 16M bytes address space, three instruction queue buffers, and two data buffers for high-speed instruction execution. The CPU is a 16-bit parallel processor that can also be switched to perform 8-bit parallel processing. This microcomputer is suitable for office, business, and industrial equipment controller that require high-speed processing of large data.

Since general purpose PROM writer can be used for the built-in PROM, this chip is suitable for small quantity production runs. For program development, the M37710E4BFS with erasable ROM that is housed in a windowed ceramic .CC is also provided.

FEATURES

- Number of basic instructions..... 103
- Memory size PROM..... 32K bytes
RAM..... 1024 bytes
- Instruction execution time
The fastest instruction at 25MHz frequency 160ns
- Single power supply..... 5V±10%
- Low power dissipation (at 25MHz frequency)
..... 95mW (Typ.)
- Interrupts 19 types 7 levels
- Multiple function 16-bit timer 5+3
(Pulse motor drive waveform can be output.)
- UART (may also be synchronous) 2
- 10-bit A-D converter..... 8-channel inputs
- 8-bit D-A converter 2-channel outputs
- 12-bit watchdog timer
- Programmable input/output
(ports P0, P1, P2, P3, P4, P5, P6, P7, P8)..... 68



APPLICATION

Control devices for office equipment such as copiers, printers, typewriters, facsimiles, word processors, and personal computers

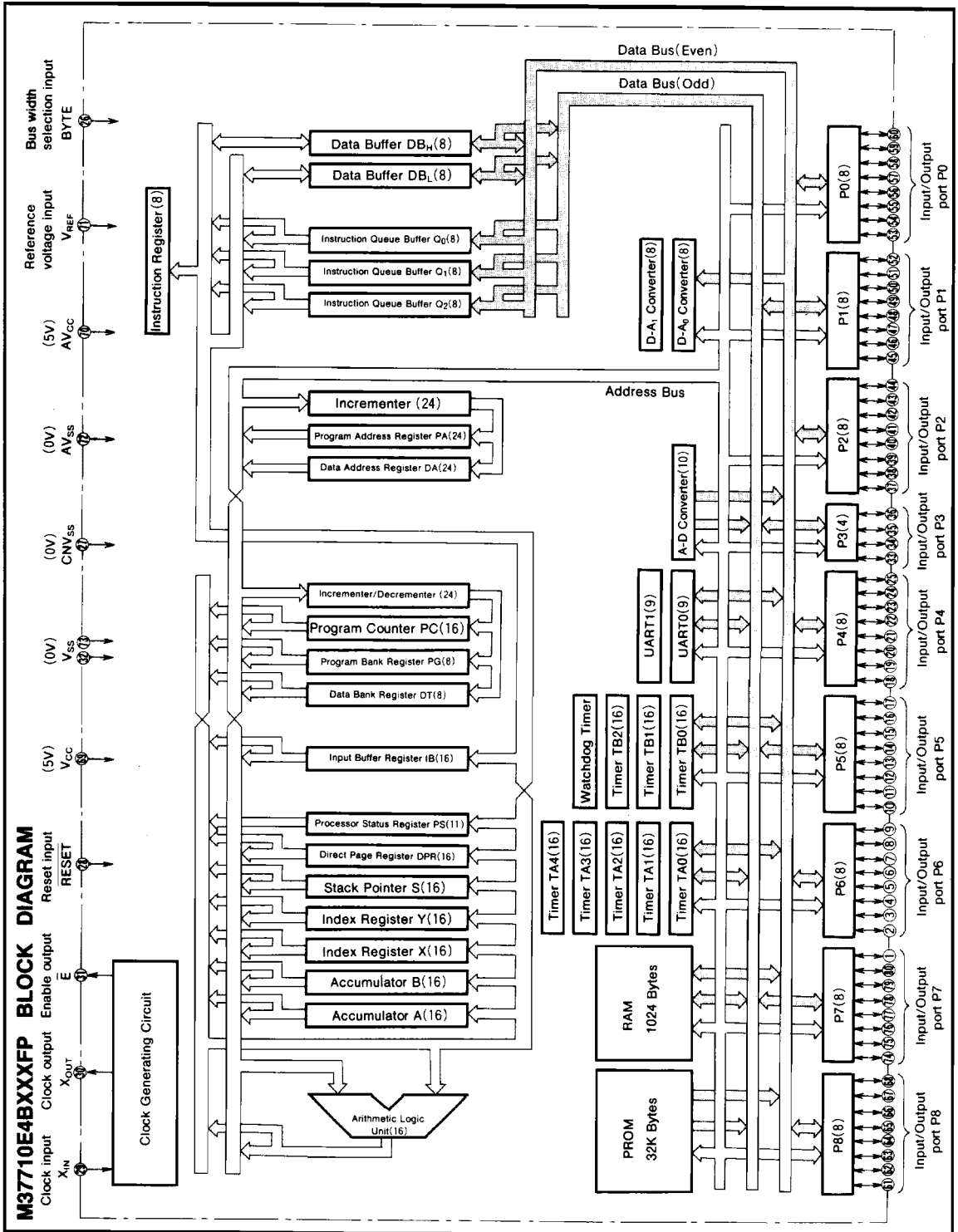
Control devices for industrial equipment such as communication and measuring instruments

NOTE

- (1) Do not use the M37710E4BFS for mass production because it is a tool for program development (for evaluation).
- (2) Refer to "Chapter 5 PRECAUTIONS" when using this microcomputer.

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FUNCTIONS OF M37710E4BXXXFP

Parameter		Functions
Number of basic instructions		103
Instruction execution time		160ns (the fastest instruction at external clock 25MHz frequency)
Memory size	PROM	32K bytes
	RAM	1024 bytes
Input/Output ports	P0~P2, P4~P8	8-bitX 8
	P3	4-bitX 1
Multi-function timers	TA0, TA1, TA2, TA3, TA4	16-bitX 5
	TB0, TB1, TB2	16-bitX 3
Serial I/O		(UART or clock synchronous serial I/O)X2
A-D converter		10-bitX 1 (8 channels)
D-A converter		8-bitX 2
Watchdog timer		12-bitX 1
Interrupts		3 external types, 16 internal types (Each interrupt can be set the priority levels to 0 ~ 7.)
Clock generating circuit		Built-in(externally connected to a ceramic resonator or quartz crystal resonator)
Supply voltage		5 V±10%
Power dissipation		95mW(at external clock 25MHz frequency)
Input/Output characteristic	Input/Output voltage	5 V
	Output current	5 mA
Memory expansion		Maximum 16M bytes
Operating temperature range		-20~85°C
Device structure		CMOS high-performance silicon gate process
Package	M37710E4BXXXFP	80-pin plastic molded QFP
	M37710E4BFS	80-pin ceramic LCC (with a window)

PIN DESCRIPTION

Pin	Name	Input/Output	Functions
V _{CC} , V _{SS}	Power supply		Supply 5 V±10% to V _{CC} and 0 V to V _{SS} .
CNV _{SS}	CNV _{SS} input	Input	This pin controls the processor mode. Connect to V _{SS} for single-chip mode, and to V _{CC} for external ROM types.
$\overline{\text{RESET}}$	Reset input	Input	To enter the reset state, this pin must be kept at a "L" condition which should be maintained for the required time.
X _{IN}	Clock input	Input	These are I/O pins of internal clock generating circuit. Connect a ceramic or quartz crystal resonator between X _{IN} and X _{OUT} . When an external clock is used, the clock source should be connected to the X _{IN} pin and the X _{OUT} pin should be left open.
X _{OUT}	Clock output	Output	
$\overline{\text{E}}$	Enable output	Output	Data or instruction read and data write are performed when output from this pin is "L".
BYTE	Bus width selection input	Input	In memory expansion mode or microprocessor mode, this pin determines whether the external data bus is 8-bit width or 16-bit width. The width is 16 bits when "L" signal inputs and 8 bits when "H" signal inputs.
AV _{CC} AV _{SS}	Analog supply input		Power supply for the A-D converter. AV _{SS} is also used for D-A converter. Connect AV _{CC} to V _{CC} and AV _{SS} to V _{SS} externally.
V _{REF}	Reference voltage input	Input	This is reference voltage input pin for the A-D converter and the D-A converter.
P0 ₀ ~P0 ₇	I/O port P0	I/O	In single-chip mode, port P0 becomes an 8-bit I/O port. An I/O direction register is available so that each pin can be programmed for input or output. These ports are in input mode when reset. Address(A ₇ ~A ₀) is output in memory expansion mode or microprocessor mode.
P1 ₀ ~P1 ₇	I/O port P1	I/O	In single-chip mode, these pins have the same functions as port P0. When the BYTE pin is set to "L" in memory expansion mode or microprocessor mode and external data bus is 16-bit width, high-order data (D ₁₅ ~D ₈) is input or output when $\overline{\text{E}}$ output is "L" and an address (A ₁₅ ~A ₈) is output when $\overline{\text{E}}$ output is "H". If the BYTE pin is "H" that is an external data bus is 8-bit width, only address(A ₁₅ ~A ₈) is output.
P2 ₀ ~P2 ₇	I/O port P2	I/O	In single-chip mode, these pins have the same functions as port P0. In memory expansion mode or microprocessor mode low-order data(D ₇ ~D ₀) is input or output when $\overline{\text{E}}$ output is "L" and an address(A ₂₃ ~A ₁₆) is output when $\overline{\text{E}}$ output is "H".
P3 ₀ ~P3 ₃	I/O port P3	I/O	In single-chip mode, these pins have the same functions as port P0. In memory expansion mode or microprocessor mode, R/W, BHE, ALE, and HLD _A signals are output.
P4 ₀ ~P4 ₇	I/O port P4	I/O	In single-chip mode, these pins have the same functions as port P0. In memory expansion mode or microprocessor mode, P4 ₀ and P4 ₁ become $\overline{\text{HOLD}}$ and $\overline{\text{RDY}}$ input pin respectively. Functions of other pins are the same as in single-chip mode. In single-chip mode or memory expansion mode, port P4 ₂ can be programmed for ϕ_1 output pin divided the clock to X _{IN} pin by 2. In microprocessor mode, P4 ₂ always has the function as ϕ_1 output pin.
P5 ₀ ~P5 ₇	I/O port P5	I/O	In addition to having the same functions as port P0 in single-chip mode, these pins also function as I/O pins for timer A0, timer A1, timer A2 and timer A3. P5 ₀ ~P5 ₆ also function as output pins for pulse motor drive waveform.
P6 ₀ ~P6 ₇	I/O port P6	I/O	In addition to having the same functions as port P0 in single-chip mode, these pins also function as I/O pins for timer A4, external interrupt input INT ₀ , INT ₁ and INT ₂ pins, and input pins for timer B0, timer B1 and timer B2. P6 ₀ also functions as output pin for pulse motor drive waveform.
P7 ₀ ~P7 ₇	I/O port P7	I/O	In addition to having the same functions as port P0 in single-chip mode, these pins also function as analog input AN ₀ ~AN ₇ input pins. P7 ₇ also has an A-D conversion trigger input function.
P8 ₀ ~P8 ₇	I/O port P8	I/O	In addition to having the same functions as port P0 in single-chip mode, these pins also function as R _X D, T _X D, CLK, CTS/RTS pins for UART 0 and UART 1, and output pins for D-A converter.

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PIN DESCRIPTION (EPROM MODE)

Pin	Name	Input/Output	Functions
V _{CC} , V _{SS}	Power supply		Supply 5V±10% to V _{CC} and 0V to V _{SS} .
CV _{SS}	V _{PP} input	Input	Connect to V _{PP} when programming or verifying.
BYTE	V _{PP} input	Input	Connect to V _{PP} when programming or verifying.
RESET	Reset input	Input	Connect to V _{SS} .
X _{IN}	Clock input	Input	Connect a ceramic resonator between X _{IN} and X _{OUT} .
X _{OUT}	Clock output	Output	
\bar{E}	Enable output	Output	Keep open.
AV _{CC} , AV _{SS}	Analog supply input		Connect AV _{CC} to V _{CC} and AV _{SS} to V _{SS} .
V _{REF}	Reference voltage input	Input	Connect to V _{SS} .
P0~P07	Address input (A ₀ ~A ₇)	Input	Port P0 functions as the lower 8 bits address input (A ₀ ~A ₇).
P1~P17	Address input (A ₈ ~A ₁₅)	Input	Port P1~P17 functions as the higher 8 bits address input (A ₈ ~A ₁₅). In 256K mode, connect P17 to V _{CC} .
P2~P27	Data I/O (D ₀ ~D ₇)	I/O	Port P2 functions as the 8 bits data bus (D ₀ ~D ₇).
P3~P33	Input port P3	Input	Connect to V _{SS} .
P4~P47	Input port P4	Input	Connect to V _{SS} .
P5~P57	Control signal input	Input	P5 ₀ *, P5 ₁ and P5 ₂ functions as PGM*, \bar{OE} and \bar{CE} input pin respectively. Connect P5 ₃ , P5 ₄ and P5 ₅ to V _{CC} . Connect P5 ₆ to V _{SS} in 256K mode and to V _{CC} in 1M mode. Connect P5 ₇ to V _{SS} .
P6~P67	Input port P6	Input	Connect to V _{SS} .
P7~P77	Input port P7	Input	Connect to V _{SS} .
P8~P87	Input port P8	Input	Connect to V _{SS} .

* : It is available in 1M mode.

BASIC FUNCTION BLOCKS

The M37710E4BXXXFP has the same functions as the M37710M4BXXXFP except that the built-in ROM is PROM. Therefore, refer to the section on the M37710M4BXXXFP.

MEMORY

The memory map is shown in Figure 1.

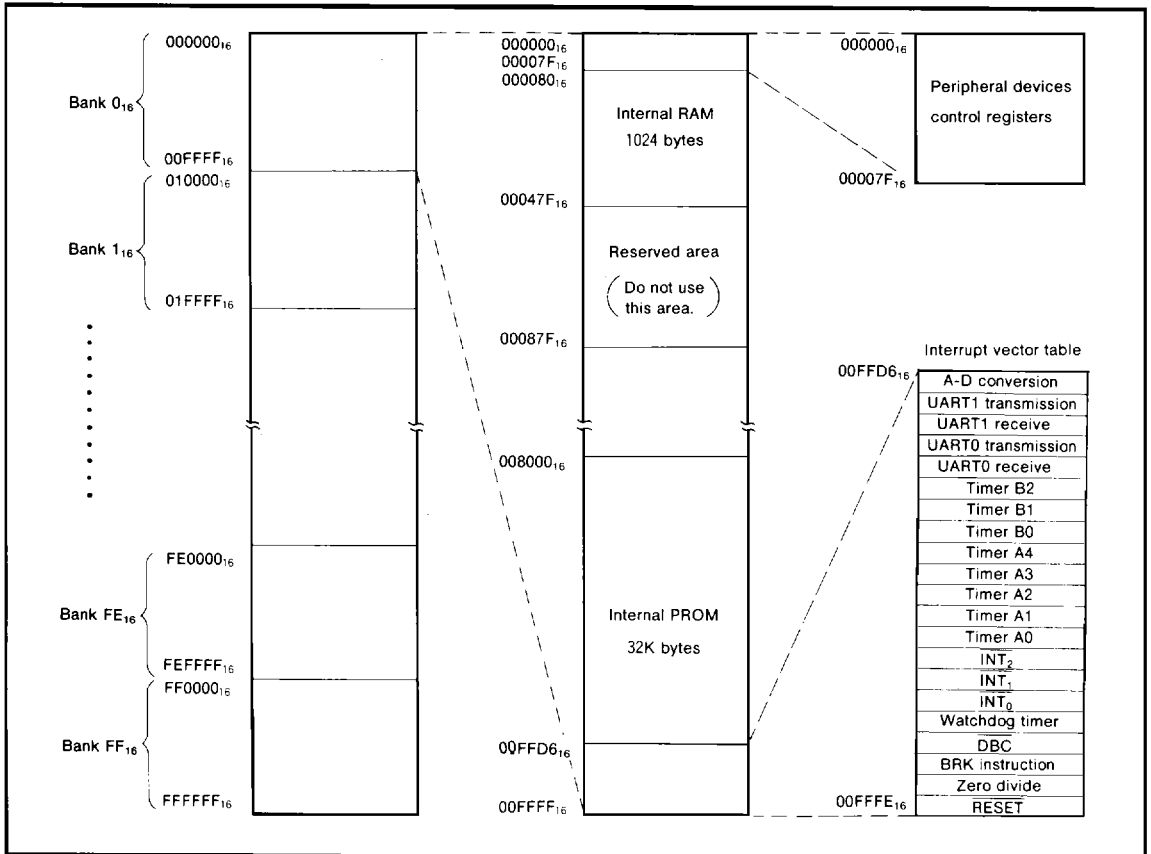


Fig. 1 Memory map

M37710E4BXXXFP
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EPROM MODE

The M37710E4BXXXFP features an EPROM mode in addition to its normal modes. When the RESET signal level is "L", the chip automatically enters the EPROM mode. Table 1 list the correspondence between pins and Figure 2 shows the pin connections in the EPROM mode.

There are two EPROM modes. One is the 256K mode for the EPROM that is equivalent to the M5M27C256K, and the other is the 1M mode for the EPROM that is equivalent to the M5M27C101K. 256K mode is selected when port P5₆ is set to "L" level, and 1M mode is selected when it is set to "H" level.

When in the EPROM mode, ports P0, P1, P2, P5₀, P5₁, P5₂, CNV_{SS} and BYTE are used for the EPROM (equivalent to the M5M27C256K or M5M27C101K). When in this mode,

the built-in PROM can be written to or read from using these pins in the same way as with the M5M27C256K or M5M27C101K.

This chip does not have Device Identifier Mode, so that set the corresponding program algorithm. The program area should specify address 0000₁₆~7FFF₁₆ in 256K mode, and address 18000₁₆~1FFFF₁₆ in 1M mode.

Connect the clock which is either ceramic resonator or external clock to X_{IN} pin and X_{OUT} pin.

For one time PROM version, 256K mode should be recommended to write more deeply.

For EPROM version (with window), 1M mode should be recommended because EPROM version is repeated to write and erase. 1M mode is faster than 256K mode for writing.

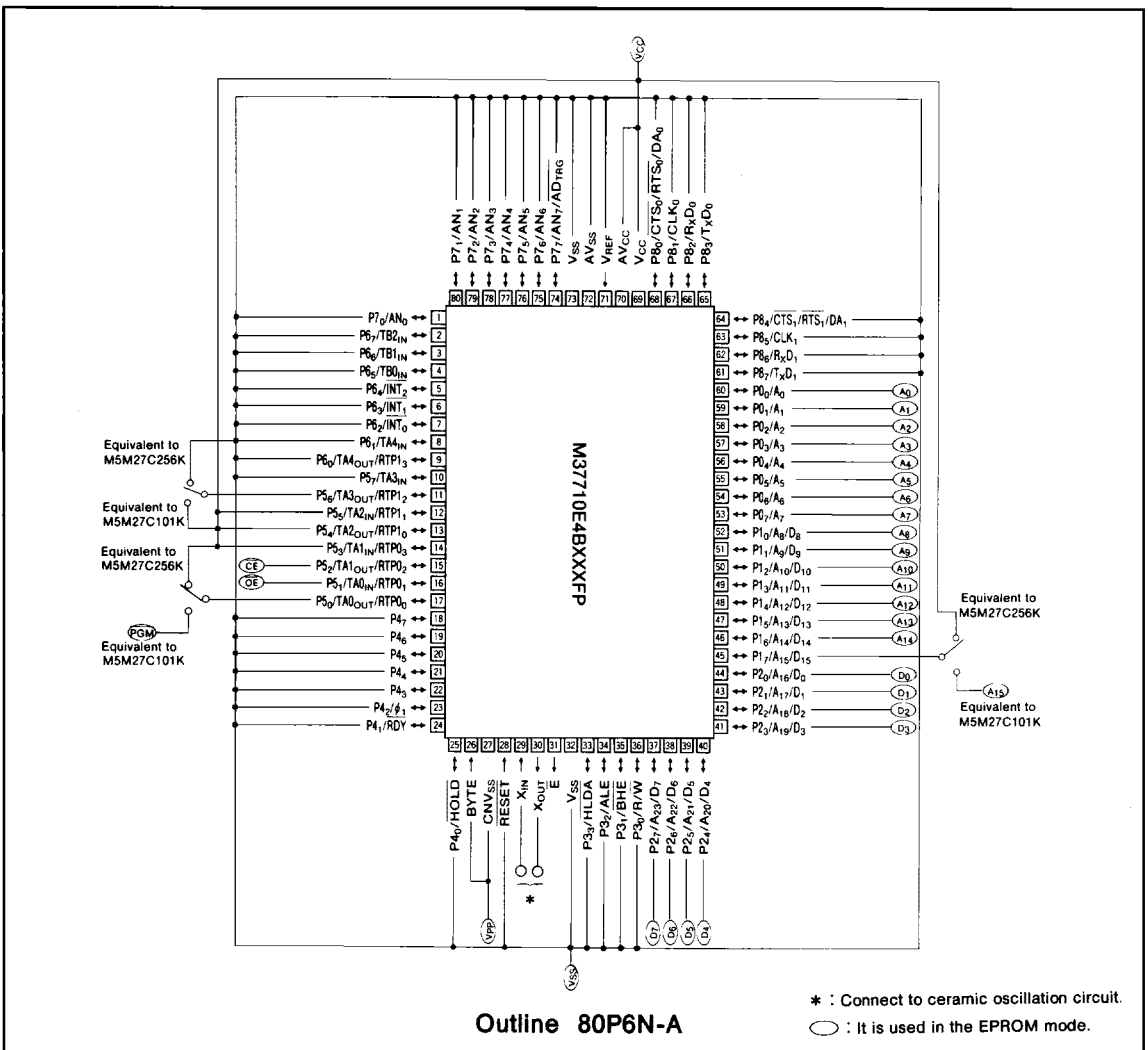


Fig. 2 Pin connection in EPROM mode

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Table 1. Pin function in EPROM mode

	M37710E4BXXXFP	M5M27C256K	M5M27C101K
V _{CC}	V _{CC}	V _{CC}	
V _{PP}	CNV _{SS} , BYTE	V _{PP}	
V _{SS}	V _{SS}	V _{SS}	
Address input	Ports P0, P1 *	A ₀ ~A ₁₄	A ₀ ~A ₁₅
Data I/O	Port P2	D ₀ ~D ₇	
CE	P5 ₂	CE	
OE	P5 ₁	OE	
PGM	P5 ₀ *	—	PGM

* : In 256K mode, connect P1₇ and P5₀ to V_{CC}.

FUNCTION IN EPROM MODE

(1) 1M mode (equivalent to the M5M27C101K)

Reading

To read the EPROM, set the \overline{CE} and \overline{OE} pins to a "L" level. Input the address of the data ($A_0 \sim A_{15}$) to be read, and the data will be output to the I/O pins $D_0 \sim D_7$. The data I/O pins will be floating when either the \overline{CE} or \overline{OE} pins are in the "H" state.

Writing

Writing must be performed in 8 bits by a byte program. To write to the EPROM, set the \overline{CE} pin to a "L" level and the \overline{OE} pin to a "H" level. The CPU will enter the program mode when 12.5V is applied to the V_{PP} pin. The address to be written to is selected with pins $A_0 \sim A_{15}$, and the data to be written is input to pins $D_0 \sim D_7$. Set the \overline{PGM} pin to a "L" level to being writing.

Erasing

To erase data on this chip, use an ultraviolet light source with a 2537 Angstrom wave length. The minimum radiation power necessary for erasing is $15 \text{ W} \cdot \text{s}/\text{cm}^2$.

Writing operation

To program the M37710E4BXXXFP, first set $V_{CC}=6\text{V}$, $V_{PP}=12.5\text{V}$, and set the address to 18000_{16} . Apply a 0.2ms write pulse, check that the data can be read, and if it cannot be read OK, repeat the procedure, applying a 0.2ms write pulse and checking that the data can be read until it can be read OK. Record the accumulated number of pulse applied (X) before the data can be read OK, and then write the data again, applying a further once this number of pulses ($0.2 \times X \text{ ms}$).

When this series of write operations is complete, increment the address, and continue to repeat the procedure above until the last address has been reached.

Finally, when all addresses have been written, read with $V_{CC}=V_{PP}=5\text{V}$ (or $V_{CC}=V_{PP}=5.5\text{V}$).

Table 2. I/O signal in each mode

Mode	Pin					
	\overline{CE}	\overline{OE}	\overline{PGM}	V_{PP}	V_{CC}	Data I/O
Read-out	V_{IL}	V_{IL}	X	5 V	5 V	Output
Output	V_{IL}	V_{IH}	X	5 V	5 V	Floating
Disable	V_{IH}	X	X	5 V	5 V	Floating
Programming	V_{IL}	V_{IH}	V_{IL}	12.5V	6 V	Input
Programming Verify	V_{IL}	V_{IL}	V_{IH}	12.5V	6 V	Output
Program Disable	V_{IH}	V_{IH}	V_{IH}	12.5V	6 V	Floating

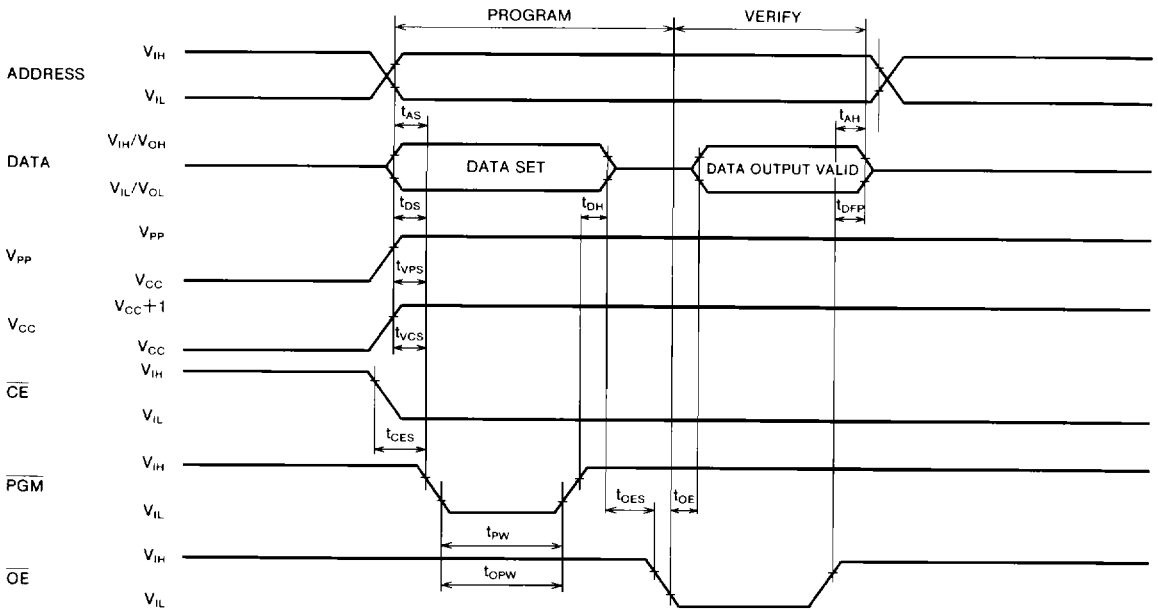
Note 1 : An X indicates either V_{IL} or V_{IH} .

Program operation (equivalent to the M5M27C101K)

AC ELECTRICAL CHARACTERISTICS ($T_a=25 \pm 5^\circ\text{C}$, $V_{CC}=6\text{V} \pm 0.25\text{V}$, $V_{PP}=12.5 \pm 0.3\text{V}$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
t_{AS}	Address setup time		2			μs
t_{OES}	\overline{OE} setup time		2			μs
t_{DS}	Data setup time		2			μs
t_{AH}	Address hold time		0			μs
t_{DH}	Data hold time		2			μs
t_{DFP}	Output enable to output float delay		0		130	ns
t_{VCS}	V_{CC} setup time		2			μs
t_{VPS}	V_{PP} setup time		2			μs
t_{PW}	\overline{PGM} pulse width		0.19	0.2	0.21	ms
t_{OPW}	\overline{PGM} over program pulse width		0.19		5.25	ms
t_{CES}	\overline{CE} setup time		2			μs
t_{OE}	Data valid from \overline{OE}				150	ns

AC waveforms



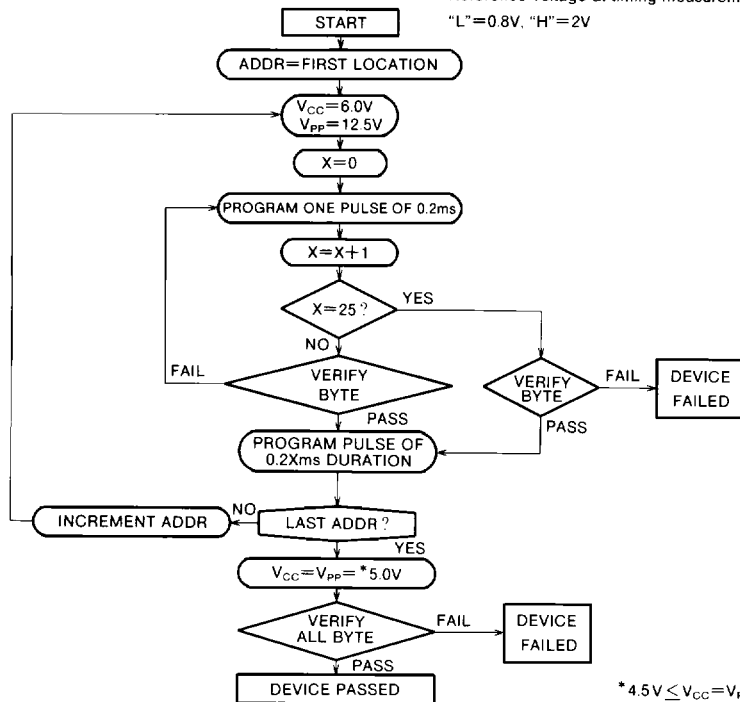
Test conditions for A.C. characteristics

Input voltage : $V_{IL}=0.45V$, $V_{IH}=2.4V$

Input rise and fall times (10%~90%) : $\leq 20ns$

Reference voltage at timing measurement : Input, Output
 "L" = 0.8V, "H" = 2V

Programming algorithm flow chart



* $4.5V \leq V_{CC} = V_{PP} \leq 5.5V$

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(2) 256K mode (equivalent to the M5M27C256K)

Reading

To read the EPROM, set the \overline{CE} and \overline{OE} pins to a "L" level. Input the address of the data ($A_0 \sim A_{14}$) to be read, and the data will be output to the I/O pins $D_0 \sim D_7$. The data I/O pins will be floating when either the \overline{CE} or \overline{OE} pins are in the "H" state.

Writing

To write to the EPROM, set the \overline{OE} pin to a "H" level. The CPU will enter the program mode when V_{PP} is applied to the V_{PP} pin. The address to be written to is selected with pins $A_0 \sim A_{14}$, and the data to be written is input to pins $D_0 \sim D_7$. Set the \overline{CE} pin to a "L" level to being writing.

Erasing

To erase data on this chip, use an ultraviolet light source with a 2537 Angstrom wave length. The minimum radiation power necessary for erasing is $15 \text{ W} \cdot \text{s}/\text{cm}^2$.

Writing operation

To program the M37710E4BXXXFP, first set $V_{CC}=6\text{V}$, $V_{PP}=12.5\text{V}$, and set the address to "0". Apply a 1ms write pulse, check that the data can be read, and if it cannot be read OK, repeat the procedure, applying a 1ms write pulse and checking that the data can be read until it can be read OK. Record the accumulated number of pulse applied (X) before the data can be read OK, and then write the data again, applying a further three times this number of pulses ($3X \text{ X ms}$).

When this series of write operations is complete, increment the address, and continue to repeat the procedure above until the last address has been reached.

Finally, when all addresses have been written, read with $V_{CC}=V_{PP}=5\text{V}$ (or $V_{CC}=V_{PP}=5.5\text{V}$).

Table 3. I/O signal in each mode

Mode	Pin		V_{PP}	V_{CC}	Data I/O
	\overline{CE}	\overline{OE}			
Read-out	V_{IL}	V_{IL}	5 V	5 V	Output
Output	V_{IL}	V_{IH}	5 V	5 V	Floating
Disable	V_{IH}	X	5 V	5 V	Floating
Programming	V_{IL}	V_{IH}	12.5 V	6 V	Input
Programming Verify	V_{IH}	V_{IL}	12.5 V	6 V	Output
Program Disable	V_{IH}	V_{IH}	12.5 V	6 V	Floating

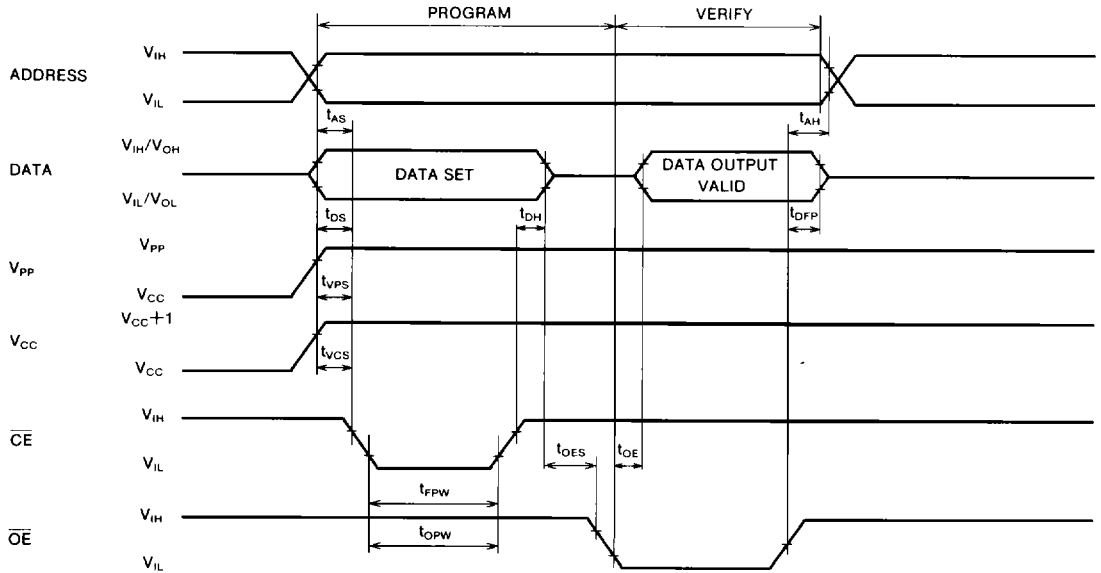
Note 1 : An X indicates either V_{IL} or V_{IH} .

Program operation (equivalent to the M5M27C256K)

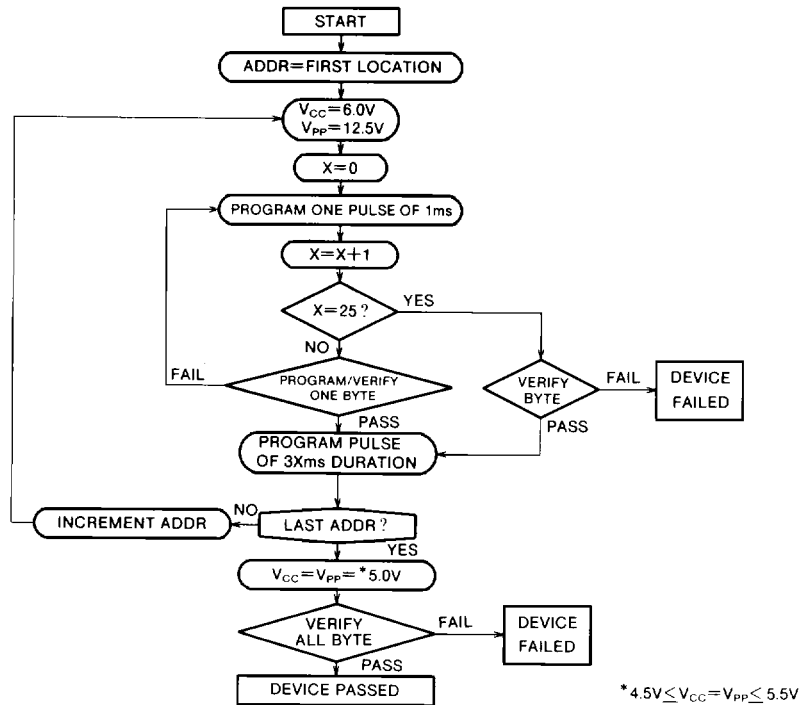
AC ELECTRICAL CHARACTERISTICS ($T_a=25 \pm 5^\circ\text{C}$, $V_{CC}=6\text{V} \pm 0.25\text{V}$, $V_{PP}=12.5 \pm 0.3\text{V}$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
t_{AS}	Address setup time		2			μs
t_{OES}	\overline{OE} setup time		2			μs
t_{DS}	Data setup time		2			μs
t_{AH}	Address hold time		0			μs
t_{DH}	Data hold time		2			μs
t_{DFP}	Output enable to output float delay		0		130	ns
t_{VCS}	V_{CC} setup time		2			μs
t_{VPS}	V_{PP} setup time		2			μs
t_{FPW}	\overline{CE} initial program pulse width		0.95	1	1.05	ms
t_{OPW}	\overline{CE} over program pulse width		2.85		78.75	ms
t_{OE}	Data valid from \overline{OE}				150	ns

AC waveforms



Programming algorithm flow chart



SAFETY INSTRUCTIONS

- (1) Sunlight and fluorescent lamp contain light that can erase written information. When using in read mode, be sure to cover the transparent glass portion with a seal or other materials (ceramic package product).
- (2) Mitsubishi Electric corp. provides the seal for covering the transparent glass. Take care that the seal does not touch the read pins (ceramic package product).
- (3) Clean the transparent glass before erasing. Fingers' fat and paste disturb the passage of ultraviolet rays and may affect badly the erasure capability (ceramic package product).
- (4) A high voltage is used for writing. Take care that over-voltage is not applied. Take care especially at power on.
- (5) The programmable M37710E4BFP that are shipped in blank is also provided. For the M37710E4BFP, Mitsubishi Electric corp. does not perform PROM write test and screening following the assembly processes. To improve reliability after write, performing write and test according to the flow below before use is recommended.

ADDRESSING MODES

The M37710E4BXXXFP has 28 powerful addressing modes. Refer to the MELPS 7700 addressing mode description for the details of each addressing mode.

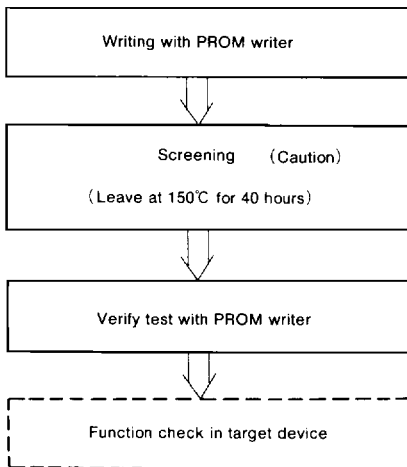
MACHINE INSTRUCTION LIST

The M37710E4BXXXFP has 103 machine instructions. Refer to the MELPS 7700 machine instruction list for details.

DATA REQUIRED FOR PROM ORDERING

Please send the following data for writing to PROM.

- (1) M37710E4BXXXFP writing to PROM order confirmation form
- (2) 80P6N mark specification form
- (3) ROM data (EPROM 3 sets)



Caution : Never expose to 150 °C exceeding 100 hours.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Conditions	Ratings	Unit
V _{CC}	Supply voltage		-0.3~7	V
AV _{CC}	Analog supply voltage		-0.3~7	V
V _I	Input voltage RESET, CNV _{SS} , BYTE		-0.3~12(Note 1)	V
V _I	Input voltage P0~P07, P10~P17, P20~P27, P30~P33, P40~P47, P50~P57, P60~P67, P70~P77, P80~P87, V _{REF} , X _{IN}		-0.3~V _{CC} +0.3	V
V _O	Output voltage P0~P07, P10~P17, P20~P27, P30~P33, P40~P47, P50~P57, P60~P67, P70~P77, P80~P87, X _{OUT} , E		-0.3~V _{CC} +0.3	V
P _d	Power dissipation	T _a =25°C	300	mW
T _{opr}	Operating temperature		-20~85	°C
T _{stg}	Storage temperature		-40~150	°C

Note 1. Input voltage for CNV_{SS} and BYTE pins is 13V in writing to PROM.

RECOMMENDED OPERATING CONDITIONS (V_{CC}=5V±10%, T_a=-20~85°C, unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min.	Typ.	Max.	
V _{CC}	Supply voltage	4.5	5.0	5.5	V
AV _{CC}	Analog supply voltage		V _{CC}		V
V _{SS}	Supply voltage		0		V
AV _{SS}	Analog supply voltage		0		V
V _{IH}	High-level input voltage P0~P07, P30~P33, P40~P47, P50~P57, P60~P67, P70~P77, P80~P87, X _{IN} , RESET, CNV _{SS} , BYTE	0.8V _{CC}		V _{CC}	V
V _{IH}	High-level input voltage P10~P17, P20~P27 (in single-chip mode)	0.8V _{CC}		V _{CC}	V
V _{IH}	High-level input voltage P10~P17, P20~P27 (in memory expansion mode and microprocessor mode)	0.5V _{CC}		V _{CC}	V
V _{IL}	Low-level input voltage P0~P07, P30~P33, P40~P47, P50~P57, P60~P67, P70~P77, P80~P87, X _{IN} , RESET, CNV _{SS} , BYTE	0		0.2V _{CC}	V
V _{IL}	Low-level input voltage P10~P17, P20~P27 (in single-chip mode)	0		0.2V _{CC}	V
V _{IL}	Low-level input voltage P10~P17, P20~P27 (in memory expansion mode and microprocessor mode)	0		0.16V _{CC}	V
I _{OH(peak)}	High-level peak output current P0~P07, P10~P17, P20~P27, P30~P33, P40~P47, P50~P57, P60~P67, P70~P77, P80~P87			-10	mA
I _{OH(avg)}	High-level average output current P0~P07, P10~P17, P20~P27, P30~P33, P40~P47, P50~P57, P60~P67, P70~P77, P80~P87			-5	mA
I _{OL(peak)}	Low-level peak output current P0~P07, P10~P17, P20~P27, P30~P33, P40~P47, P50~P57, P60~P67, P70~P77, P80~P87			10	mA
I _{OL(avg)}	Low-level average output current P0~P07, P10~P17, P20~P27, P30~P33, P40~P47, P50~P57, P60~P67, P70~P77, P80~P87			5	mA
f(X _{IN})	External clock frequency input			25	MHz

Note 2. Average output current is the average value of a 100ms interval.

- The sum of I_{OL(peak)} for ports P0, P1, P2, P3, and P8 must be 80mA or less, the sum of I_{OH(peak)} for ports P0, P1, P2, P3, and P8 must be 80mA or less, the sum of I_{OL(peak)} for ports P4, P5, P6, and P7 must be 80mA or less, and the sum of I_{OH(peak)} for ports P4, P5, P6, and P7 must be 80mA or less.

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ELECTRICAL CHARACTERISTICS ($V_{CC}=5V$, $V_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=25MHz$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V_{OH}	High-level output voltage P0 ₀ ~P0 ₇ , P1 ₀ ~P1 ₇ , P2 ₀ ~P2 ₇ , P3 ₀ , P3 ₁ , P3 ₃ , P4 ₀ ~P4 ₇ , P5 ₀ ~P5 ₇ , P6 ₀ ~P6 ₇ , P7 ₀ ~P7 ₇ , P8 ₀ ~P8 ₇	$I_{OH}=-10mA$	3			V
V_{OH}	High-level output voltage P0 ₀ ~P0 ₇ , P1 ₀ ~P1 ₇ , P2 ₀ ~P2 ₇ , P3 ₀ , P3 ₁ , P3 ₃	$I_{OH}=-400\mu A$	4.7			V
V_{OH}	High-level output voltage P3 ₂	$I_{OH}=-10mA$ $I_{OH}=-400\mu A$	3.1 4.8			V
V_{OH}	High-level output voltage \bar{E}	$I_{OH}=-10mA$ $I_{OH}=-400\mu A$	3.4 4.8			V
V_{OL}	Low-level output voltage P0 ₀ ~P0 ₇ , P1 ₀ ~P1 ₇ , P2 ₀ ~P2 ₇ , P3 ₀ , P3 ₁ , P3 ₃ , P4 ₀ ~P4 ₇ , P5 ₀ ~P5 ₇ , P6 ₀ ~P6 ₇ , P7 ₀ ~P7 ₇ , P8 ₀ ~P8 ₇	$I_{OL}=10mA$			2	V
V_{OL}	Low-level output voltage P0 ₀ ~P0 ₇ , P1 ₀ ~P1 ₇ , P2 ₀ ~P2 ₇ , P3 ₀ , P3 ₁ , P3 ₃	$I_{OL}=2mA$			0.45	V
V_{OL}	Low-level output voltage P3 ₂	$I_{OL}=10mA$ $I_{OL}=2mA$			1.9 0.43	V
V_{OL}	Low-level output voltage \bar{E}	$I_{OL}=10mA$ $I_{OL}=2mA$			1.6 0.4	V
$V_{T+}-V_{T-}$	Hysteresis \overline{HOLD} , \overline{RDY} , TA0 _{IN} ~TA4 _{IN} , TB0 _{IN} ~TB2 _{IN} , INT ₀ ~INT ₂ , AD _{TRG} , CTS ₀ , CTS ₁ , CLK ₀ , CLK ₁		0.4		1	V
$V_{T+}-V_{T-}$	Hysteresis \overline{RESET}		0.2		0.5	V
$V_{T+}-V_{T-}$	Hysteresis X _{IN}		0.1		0.3	V
I_{IH}	High-level input current P0 ₀ ~P0 ₇ , P1 ₀ ~P1 ₇ , P2 ₀ ~P2 ₇ , P3 ₀ ~P3 ₃ , P4 ₀ ~P4 ₇ , P5 ₀ ~P5 ₇ , P6 ₀ ~P6 ₇ , P7 ₀ ~P7 ₇ , P8 ₀ ~P8 ₇ , X _{IN} , \overline{RESET} , CNV _{SS} , BYTE	$V_i=5V$			5	μA
I_{IL}	Low-level input current P0 ₀ ~P0 ₇ , P1 ₀ ~P1 ₇ , P2 ₀ ~P2 ₇ , P3 ₀ ~P3 ₃ , P4 ₀ ~P4 ₇ , P5 ₀ ~P5 ₇ , P6 ₀ ~P6 ₇ , P7 ₀ ~P7 ₇ , P8 ₀ ~P8 ₇ , X _{IN} , \overline{RESET} , CNV _{SS} , BYTE	$V_i=0V$			-5	μA
V_{RAM}	RAM hold voltage	When clock is stopped.	2			V
I_{CC}	Power supply current	In single-chip mode output only pin is open and other pins are V _{SS} during reset.	$f(X_{IN})=25MHz$, square waveform $T_a=25^\circ C$ when clock is stopped.	19	38	mA
			$T_a=85^\circ C$ when clock is stopped.		20	μA

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A-D CONVERTER CHARACTERISTICS ($V_{CC}=AV_{CC}=5V$, $V_{SS}=AV_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=25MHz$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
—	Resolution	$V_{REF}=V_{CC}$			10	Bits
—	Absolute accuracy	$V_{REF}=V_{CC}$			± 3	LSB
R_{LADDER}	Ladder resistance	$V_{REF}=V_{CC}$	5		20	k Ω
t_{CONV}	Conversion time		9.44			μs
V_{REF}	Reference voltage		2		V_{CC}	V
V_{IA}	Analog input voltage		0		V_{REF}	V

D-A CONVERTER CHARACTERISTICS ($V_{CC}=5V$, $V_{SS}=AV_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=25MHz$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
—	Resolution				8	Bits
—	Absolute accuracy				1.0	%
t_{SU}	Set time				3	μs
R_O	Output resistance		1	2.5	4	k Ω
I_{VREF}	Reference power input current	(Note 1)			3.2	mA

Note 1. One D-A converter is used, and the value of D-A register for unused D-A converter is "00₁₆".
 Current that flows to the ladder resistance of A-D converter is excluded.

TIMING REQUIREMENTS ($V_{CC}=5V\pm 10\%$, $V_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=25MHz$, unless otherwise noted)

External clock input

Symbol	Parameter	Limits		Unit
		Min.	Max.	
t_C	External clock input cycle time	40		ns
$t_{W(H)}$	External clock input high-level pulse width	15		ns
$t_{W(L)}$	External clock input low-level pulse width	15		ns
t_r	External clock rise time		8	ns
t_f	External clock fall time		8	ns

Single-chip mode

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{SU(P0D-E)}$	Port P0 input setup time	60		ns
$t_{SU(P1D-E)}$	Port P1 input setup time	60		ns
$t_{SU(P2D-E)}$	Port P2 input setup time	60		ns
$t_{SU(P3D-E)}$	Port P3 input setup time	60		ns
$t_{SU(P4D-E)}$	Port P4 input setup time	60		ns
$t_{SU(P5D-E)}$	Port P5 input setup time	60		ns
$t_{SU(P6D-E)}$	Port P6 input setup time	60		ns
$t_{SU(P7D-E)}$	Port P7 input setup time	60		ns
$t_{SU(P8D-E)}$	Port P8 input setup time	60		ns
$t_{H(E-P0D)}$	Port P0 input hold time	0		ns
$t_{H(E-P1D)}$	Port P1 input hold time	0		ns
$t_{H(E-P2D)}$	Port P2 input hold time	0		ns
$t_{H(E-P3D)}$	Port P3 input hold time	0		ns
$t_{H(E-P4D)}$	Port P4 input hold time	0		ns
$t_{H(E-P5D)}$	Port P5 input hold time	0		ns
$t_{H(E-P6D)}$	Port P6 input hold time	0		ns
$t_{H(E-P7D)}$	Port P7 input hold time	0		ns
$t_{H(E-P8D)}$	Port P8 input hold time	0		ns

Memory expansion mode and microprocessor mode

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{SU(P1D-E)}$	Port P1 input setup time	30		ns
$t_{SU(P2D-E)}$	Port P2 input setup time	30		ns
$t_{SU(RDY-\phi_1)}$	RDY input setup time	55		ns
$t_{SU(HOLD-\phi_1)}$	HOLD input setup time	55		ns
$t_{H(E-P1D)}$	Port P1 input hold time	0		ns
$t_{H(E-P2D)}$	Port P2 input hold time	0		ns
$t_{H(\phi_1-RDY)}$	RDY input hold time	0		ns
$t_{H(\phi_1-HOLD)}$	HOLD input hold time	0		ns

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Timer A input (Count input in event counter mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TA)}$	TA _{IN} input cycle time	80		ns
$t_{W(TAH)}$	TA _{IN} input high-level pulse width	40		ns
$t_{W(TAL)}$	TA _{IN} input low-level pulse width	40		ns

Timer A input (Gating input in timer mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TA)}$	TA _{IN} input cycle time	320		ns
$t_{W(TAH)}$	TA _{IN} input high-level pulse width	160		ns
$t_{W(TAL)}$	TA _{IN} input low-level pulse width	160		ns

Timer A input (External trigger input in one-shot pulse mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TA)}$	TA _{IN} input cycle time	160		ns
$t_{W(TAH)}$	TA _{IN} input high-level pulse width	80		ns
$t_{W(TAL)}$	TA _{IN} input low-level pulse width	80		ns

Timer A input (External trigger input in pulse width modulation mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{W(TAH)}$	TA _{IN} input high-level pulse width	80		ns
$t_{W(TAL)}$	TA _{IN} input low-level pulse width	80		ns

Timer A input (Up-down input in event counter mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(UP)}$	TA _{OUT} input cycle time	2000		ns
$t_{W(UPH)}$	TA _{OUT} input high-level pulse width	1000		ns
$t_{W(UPL)}$	TA _{OUT} input low-level pulse width	1000		ns
$t_{SU(UP-TN)}$	TA _{OUT} input setup time	400		ns
$t_{H(TN-UP)}$	TA _{OUT} input hold time	400		ns

Timer B input (Count input in event counter mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TB)}$	TBI _{IN} input cycle time (one edge count)	80		ns
$t_{W(TBH)}$	TBI _{IN} input high-level pulse width (one edge count)	40		ns
$t_{W(TBL)}$	TBI _{IN} input low-level pulse width (one edge count)	40		ns
$t_{C(TB)}$	TBI _{IN} input cycle time (both edges count)	160		ns
$t_{W(TBH)}$	TBI _{IN} input high-level pulse width (both edges count)	80		ns
$t_{W(TBL)}$	TBI _{IN} input low-level pulse width (both edges count)	80		ns

Timer B input (Pulse period measurement mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TB)}$	TBI _{IN} input cycle time	320		ns
$t_{W(TBH)}$	TBI _{IN} input high-level pulse width	160		ns
$t_{W(TBL)}$	TBI _{IN} input low-level pulse width	160		ns

Timer B input (Pulse width measurement mode)

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(TB)}$	TBI _{IN} input cycle time	320		ns
$t_{W(TBH)}$	TBI _{IN} input high-level pulse width	160		ns
$t_{W(TBL)}$	TBI _{IN} input low-level pulse width	160		ns

A-D trigger input

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(AD)}$	AD _{TRG} input cycle time (minimum allowable trigger)	1000		ns
$t_{W(ADL)}$	AD _{TRG} input low-level pulse width	125		ns

Serial I/O

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{C(CK)}$	CLK _j input cycle time	200		ns
$t_{W(CKH)}$	CLK _j input high-level pulse width	100		ns
$t_{W(CKL)}$	CLK _j input low-level pulse width	100		ns
$t_{d(C-Q)}$	TxD _j output delay time		80	ns
$t_{h(C-Q)}$	TxD _j hold time	0		ns
$t_{su(D-C)}$	RxD _j input setup time	30		ns
$t_{h(C-D)}$	RxD _j input hold time	90		ns

External interrupt INT_j input

Symbol	Parameter	Limits		Unit
		Min.	Max.	
$t_{W(INH)}$	INT _j input high-level pulse width	250		ns
$t_{W(INL)}$	INT _j input low-level pulse width	250		ns

SWITCHING CHARACTERISTICS ($V_{CC}=5V\pm 10\%$, $V_{SS}=0V$, $T_a=25^\circ C$, $f(X_{IN})=25MHz$, unless otherwise noted)

Single-chip mode

Symbol	Parameter	Test conditions	Limits		Unit
			Min.	Max.	
$t_{d(E-P0Q)}$	Port P0 data output delay time	Fig. 3		80	ns
$t_{d(E-P1Q)}$	Port P1 data output delay time			80	ns
$t_{d(E-P2Q)}$	Port P2 data output delay time			80	ns
$t_{d(E-P3Q)}$	Port P3 data output delay time			80	ns
$t_{d(E-P4Q)}$	Port P4 data output delay time			80	ns
$t_{d(E-P5Q)}$	Port P5 data output delay time			80	ns
$t_{d(E-P6Q)}$	Port P6 data output delay time			80	ns
$t_{d(E-P7Q)}$	Port P7 data output delay time			80	ns
$t_{d(E-P8Q)}$	Port P8 data output delay time			80	ns

Memory expansion mode and microprocessor mode (when wait bit = "1")

Symbol	Parameter	Test conditions	Limits		Unit	
			Min.	Max.		
$t_{d(P0A-E)}$	Port P0 address output delay time	Fig. 3	12		ns	
$t_{d(E-P1Q)}$	Port P1 data output delay time (BYTE="L")			45	ns	
$t_{pxz(E-P1Z)}$	Port P1 floating start delay time (BYTE="L")			5	ns	
$t_{d(P1A-E)}$	Port P1 address output delay time			12	ns	
$t_{d(P1A-ALE)}$	Port P1 address output delay time			5	ns	
$t_{d(E-P2Q)}$	Port P2 data output delay time			45	ns	
$t_{pxz(E-P2Z)}$	Port P2 floating start delay time			5	ns	
$t_{d(P2A-E)}$	Port P2 address output delay time			12	ns	
$t_{d(P2A-ALE)}$	Port P2 address output delay time			5	ns	
$t_{d(\phi_1-HLDA)}$	HLDA output delay time			50	ns	
$t_{d(ALE-E)}$	ALE output delay time			4	ns	
$t_w(ALE)$	ALE pulse width			22	ns	
$t_{d(BHE-E)}$	BHE output delay time			20	ns	
$t_{d(R/W-E)}$	R/W output delay time			20	ns	
$t_{d(E-\phi_1)}$	ϕ_1 output delay time			0	18	ns
$t_h(E-P0A)$	Port P0 address hold time			25	ns	
$t_h(ALE-P1A)$	Port P1 address hold time (BYTE="L")			9	ns	
$t_h(E-P1Q)$	Port P1 data hold time (BYTE="L")			25	ns	
$t_{pzx(E-P1Z)}$	Port P1 floating release delay time (BYTE="L")			25	ns	
$t_h(E-P1A)$	Port P1 address hold time (BYTE="H")			25	ns	
$t_h(ALE-P2A)$	Port P2 address hold time			9	ns	
$t_h(E-P2Q)$	Port P2 data hold time			25	ns	
$t_{pzx(E-P2Z)}$	Port P2 floating release delay time			25	ns	
$t_h(E-BHE)$	BHE hold time			18	ns	
$t_h(E-R/W)$	R/W hold time			18	ns	
$t_w(EL)$	\bar{E} pulse width			50	ns	

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Memory expansion mode and microprocessor mode

(when wait bit = "0", wait selection bit = "1", and external memory area is accessed)

Symbol	Parameter	Test conditions	Limits		Unit
			Min.	Max.	
$t_d(P0A-E)$	Port P0 address output delay time	Fig. 3	12		ns
$t_d(E-P1Q)$	Port P1 data output delay time (BYTE="L")			45	ns
$tpxz(E-P1Z)$	Port P1 floating start delay time (BYTE="L")			5	ns
$t_d(P1A-E)$	Port P1 address output delay time		12		ns
$t_d(P1A-ALE)$	Port P1 address output delay time		5		ns
$t_d(E-P2Q)$	Port P2 data output delay time			45	ns
$tpxz(E-P2Z)$	Port P2 floating start delay time			5	ns
$t_d(P2A-E)$	Port P2 address output delay time		12		ns
$t_d(P2A-ALE)$	Port P2 address output delay time		5		ns
$t_d(\phi_1-HLDA)$	HLDA output delay time			50	ns
$t_d(ALE-E)$	ALE output delay time		4		ns
$t_w(ALE)$	ALE pulse width		22		ns
$t_d(BHE-E)$	BHE output delay time		20		ns
$t_d(R/W-E)$	R/W output delay time		20		ns
$t_d(E-\phi_1)$	ϕ_1 output delay time		0	18	ns
$t_h(E-P0A)$	Port P0 address hold time		25		ns
$t_h(ALE-P1A)$	Port P1 address hold time (BYTE="L")		9		ns
$t_h(E-P1Q)$	Port P1 data hold time (BYTE="L")		25		ns
$tpzx(E-P1Z)$	Port P1 floating release delay time (BYTE="L")		25		ns
$t_h(E-P1A)$	Port P1 address hold time (BYTE="H")		25		ns
$t_h(ALE-P2A)$	Port P2 address hold time		9		ns
$t_h(E-P2Q)$	Port P2 data hold time		25		ns
$tpzx(E-P2Z)$	Port P2 floating release delay time		25		ns
$t_h(E-BHE)$	BHE hold time	18		ns	
$t_h(E-R/W)$	R/W hold time	18		ns	
$t_w(EL)$	\bar{E} pulse width	130		ns	

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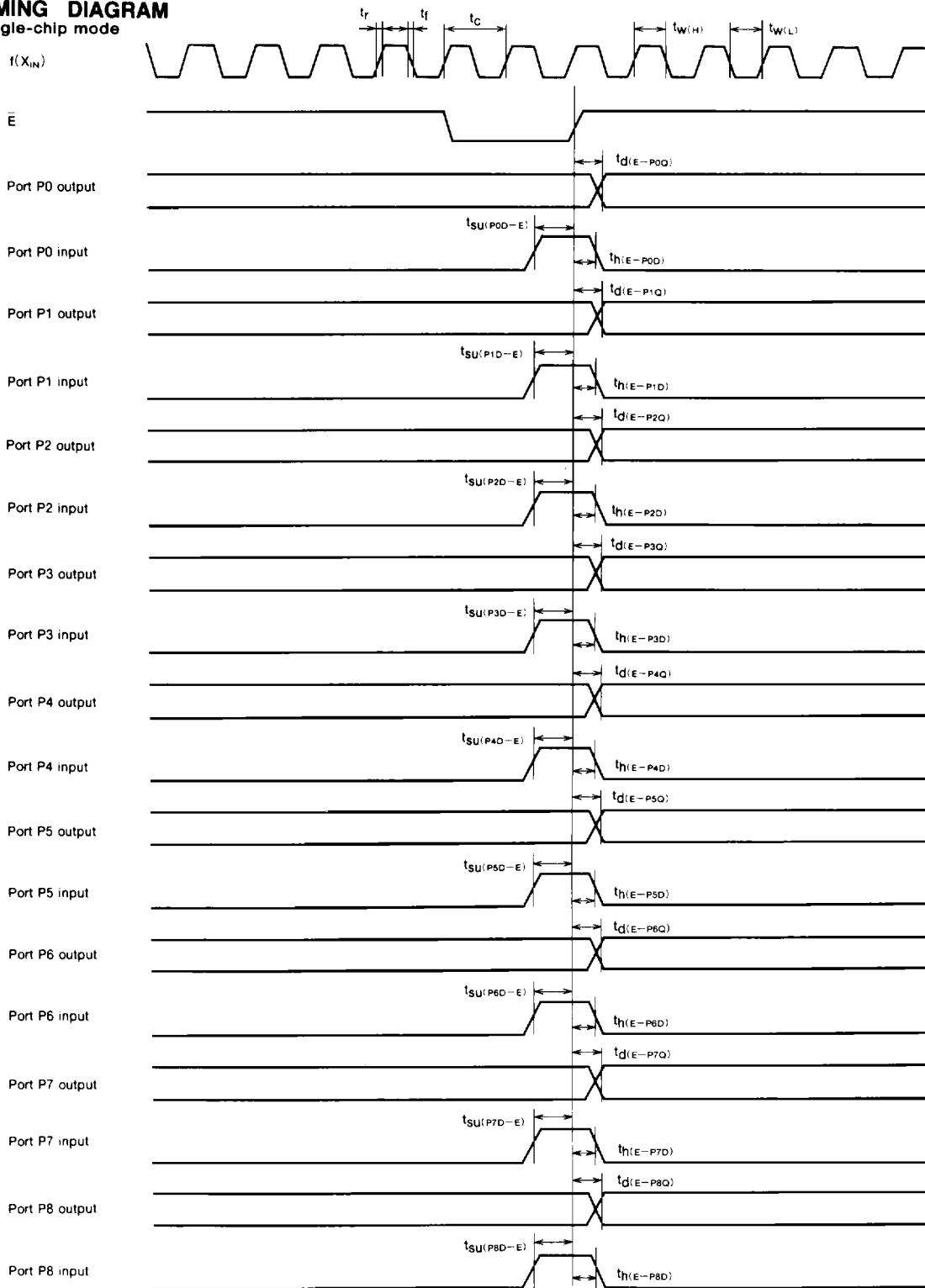
PROM VERSION of M37710M4BXXFP

Memory expansion mode and microprocessor mode

(when wait bit = "0", wait selection bit = "1", and external memory area is accessed)

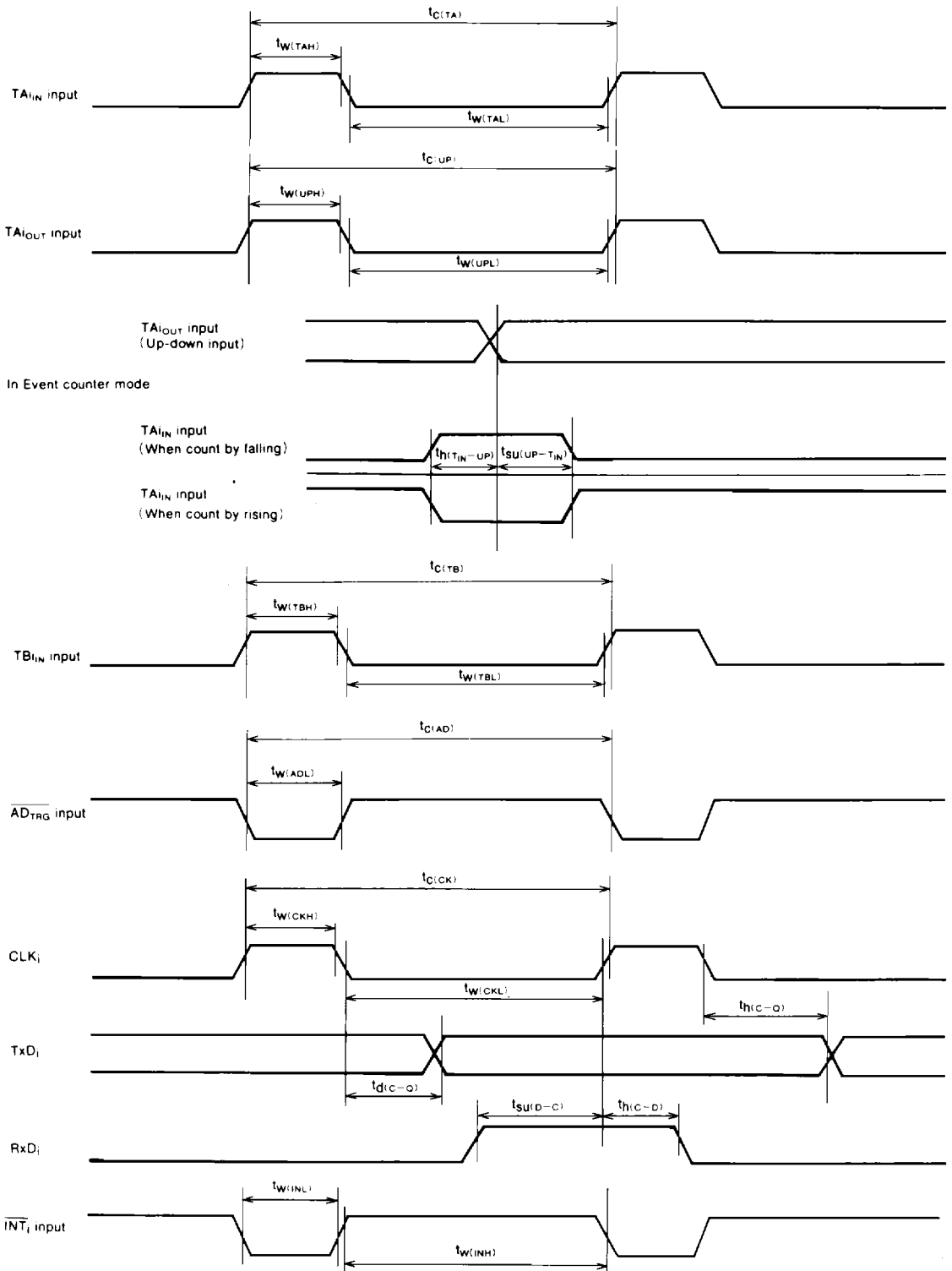
Symbol	Parameter	Test conditions	Limits		Unit
			Min.	Max.	
$t_{d(P0A-E)}$	Port P0 address output delay time	Fig. 3	12		ns
$t_{d(E-P1Q)}$	Port P1 data output delay time (BYTE="L")			45	ns
$t_{pXZ(E-P1Z)}$	Port P1 floating start delay time (BYTE="L")			5	ns
$t_{d(P1A-E)}$	Port P1 address output delay time		12		ns
$t_{d(P1A-ALE)}$	Port P1 address output delay time		5		ns
$t_{d(E-P2Q)}$	Port P2 data output delay time			45	ns
$t_{pXZ(E-P2Z)}$	Port P2 floating start delay time			5	ns
$t_{d(P2A-E)}$	Port P2 address output delay time		12		ns
$t_{d(P2A-ALE)}$	Port P2 address output delay time		5		ns
$t_{d(\phi_1-HLDA)}$	HLDA output delay time			50	ns
$t_{d(ALE-E)}$	ALE output delay time		4		ns
$t_{w(ALE)}$	ALE pulse width		22		ns
$t_{d(BHE-E)}$	BHE output delay time		20		ns
$t_{d(R/W-E)}$	R/W output delay time		20		ns
$t_{d(E-\phi_1)}$	ϕ_1 output delay time		0	18	ns
$t_{h(E-P0A)}$	Port P0 address hold time		25		ns
$t_{h(ALE-P1A)}$	Port P1 address hold time (BYTE="L")		9		ns
$t_{h(E-P1Q)}$	Port P1 data hold time (BYTE="L")		25		ns
$t_{pZX(E-P1Z)}$	Port P1 floating release delay time (BYTE="L")		25		ns
$t_{h(E-P1A)}$	Port P1 address hold time (BYTE="H")		25		ns
$t_{h(ALE-P2A)}$	Port P2 address hold time		9		ns
$t_{h(E-P2Q)}$	Port P2 data hold time		25		ns
$t_{pZX(E-P2Z)}$	Port P2 floating release delay time		25		ns
$t_{h(E-BHE)}$	BHE hold time		18		ns
$t_{h(E-R/W)}$	R/W hold time		18		ns
$t_{w(EL)}$	\bar{E} pulse width		130		ns

TIMING DIAGRAM
 Single-chip mode



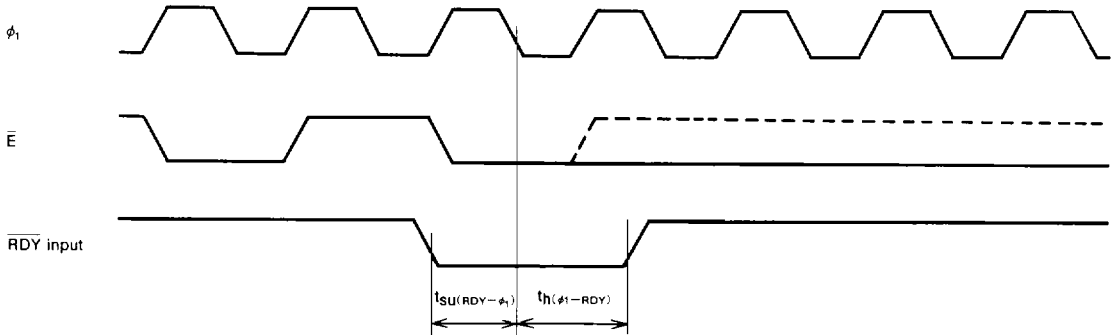
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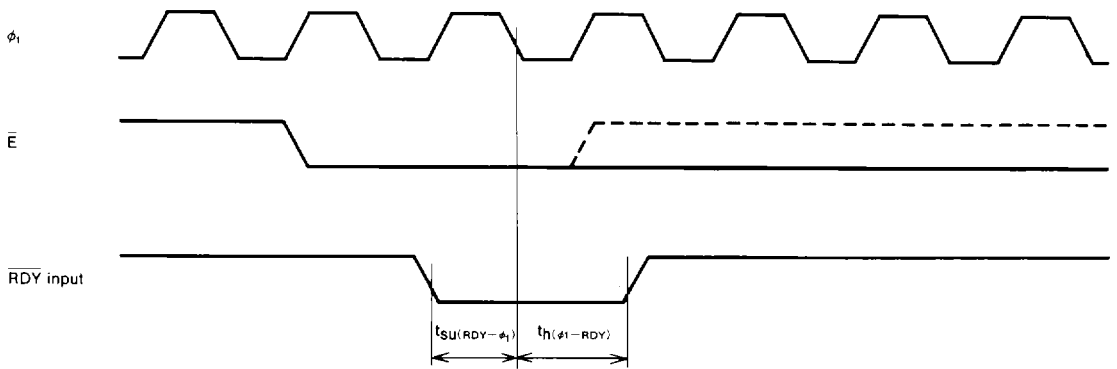


Memory expansion mode and microprocessor mode

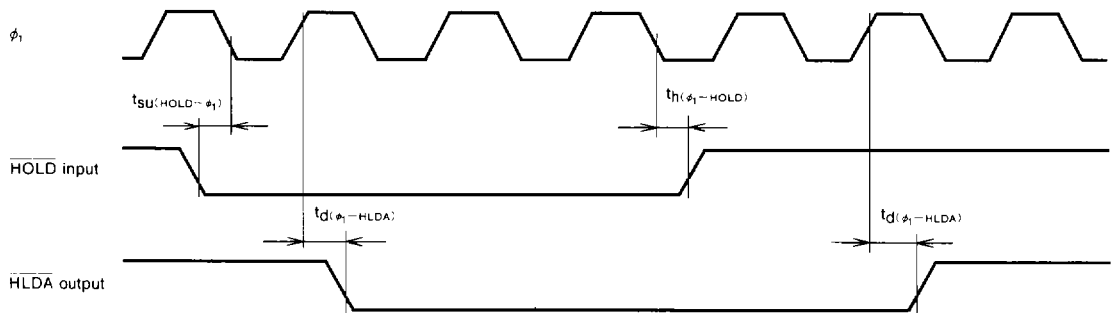
(When wait bit = "1")



(When wait bit = "0")



(When wait bit = "1" or "0" in common)



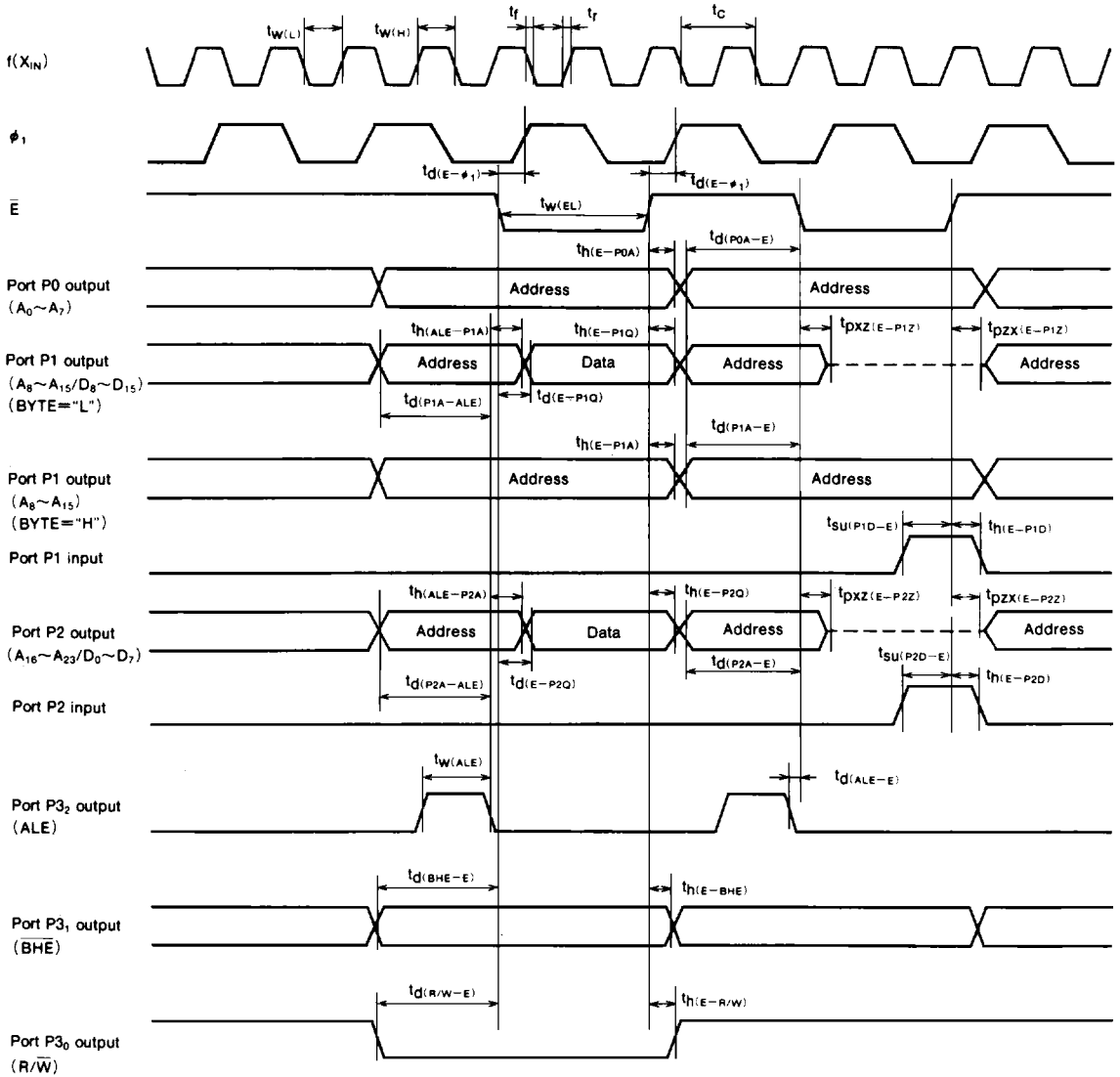
Test conditions

- $V_{CC} = 5V \pm 10\%$
- Input timing voltage : $V_{IL} = 1.0V, V_{IH} = 4.0V$
- Output timing voltage : $V_{OL} = 0.8V, V_{OH} = 2.0V$

MITSUBISHI MICROCOMPUTERS
M37710E4BXXXFP
M37710E4BFS

PROM VERSION of M37710M4BXXXFP

Memory expansion mode and microprocessor mode (When wait bit="1")



Test conditions

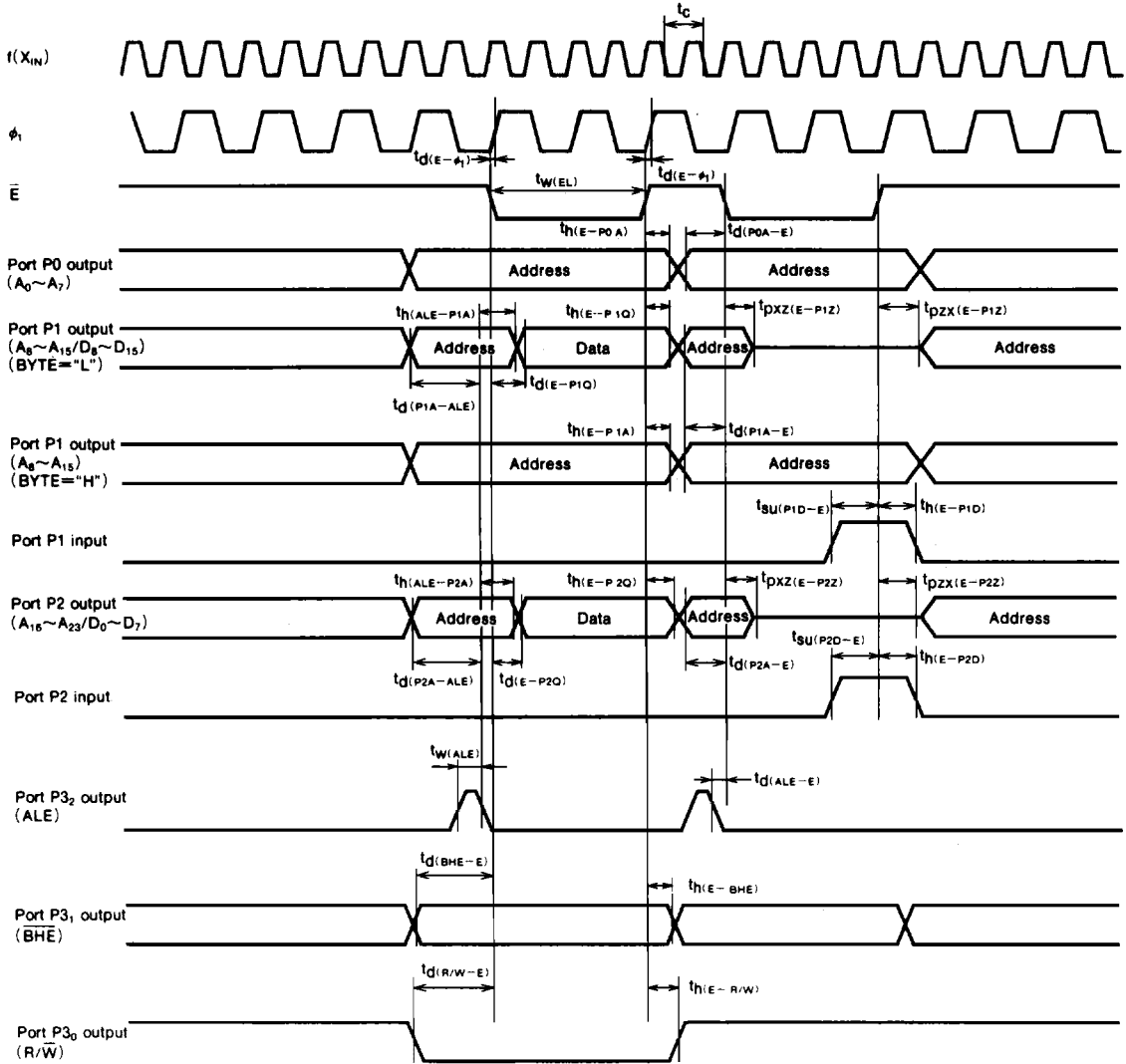
- $V_{CC}=5V \pm 10\%$
- Output timing voltage : $V_{OL}=0.8V, V_{OH}=2.0V$
- Ports P1, P2 input : $V_{IL}=0.8V, V_{IH}=2.5V$

MITSUBISHI MICROCOMPUTERS
M37710E4BXXXFP
M37710E4BFS

PROM VERSION of M37710M4BXXXFP

Memory expansion mode and microprocessor mode

(When wait bit = "0", wait selection bit = "1", and external memory area is accessed)

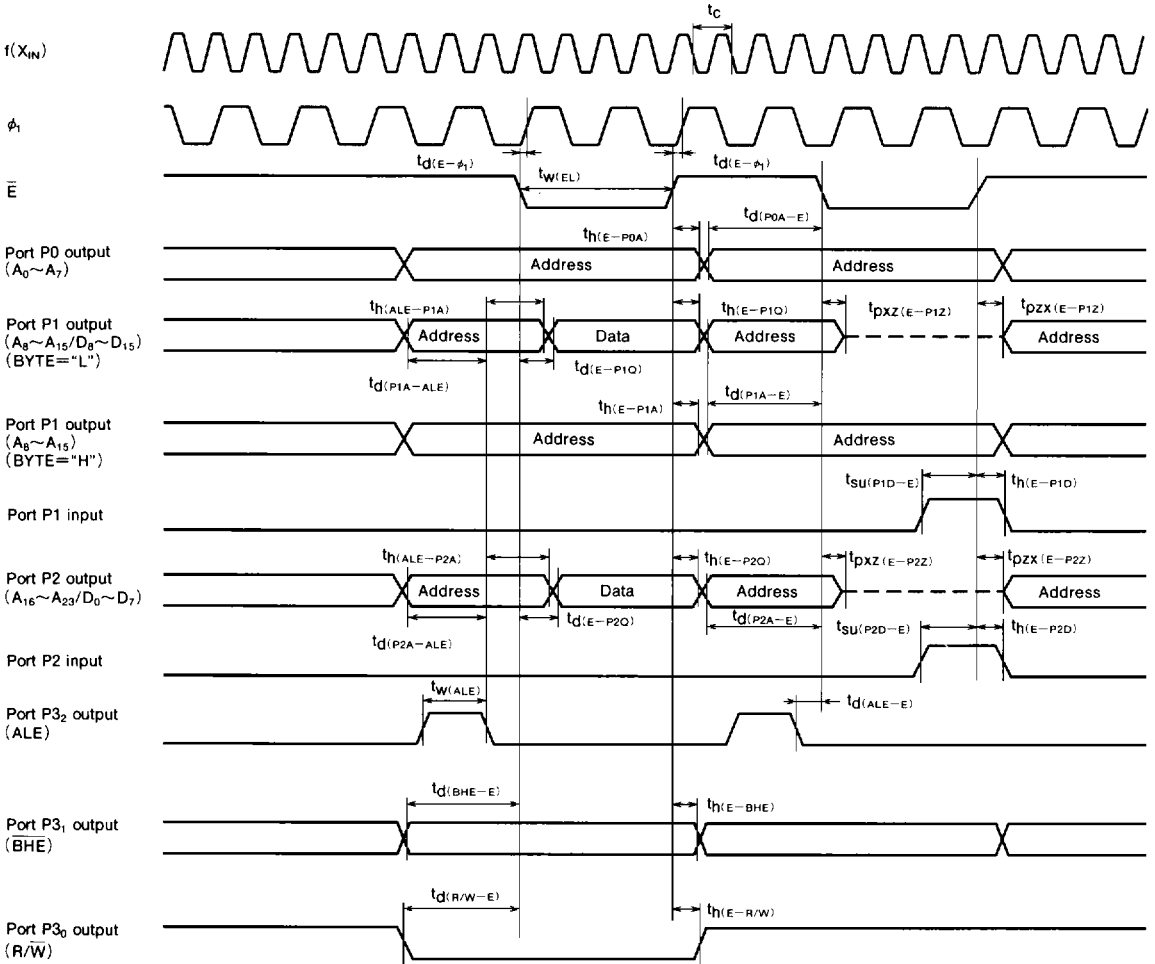


Test conditions

- $V_{CC} = 5V \pm 10\%$
- Output timing voltage : $V_{OL} = 0.8V, V_{OH} = 2.0V$
- Ports P1, P2 input : $V_{IL} = 0.8V, V_{IH} = 2.5V$

Memory expansion mode and microprocessor mode

(When wait bit = "0", wait selection bit = "0", and external memory area is accessed)



Test conditions

- $V_{CC} = 5V \pm 10\%$
- Output timing voltage : $V_{OL} = 0.8V, V_{OH} = 2.0V$
- Ports P1, P2 input : $V_{IL} = 0.8V, V_{IH} = 2.5V$